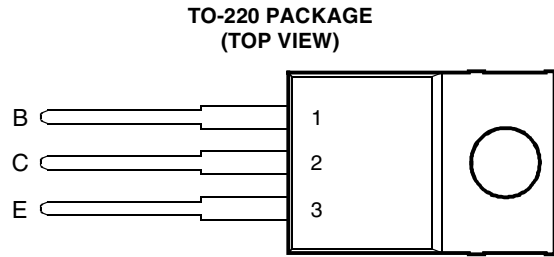


- Designed for Complementary Use with BD896, BD898, BD900 and BD902
- 70 W at 25°C Case Temperature
- 8 A Continuous Collector Current
- Minimum h_{FE} of 750 at 3V, 3A



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ($I_E = 0$)	BD895	V_{CBO}	45	V
	BD897		60	
	BD899		80	
	BD901		100	
Collector-emitter voltage ($I_B = 0$)	BD895	V_{CEO}	45	V
	BD897		60	
	BD899		80	
	BD901		100	
Base-emitter voltage		V_{EBO}	5	V
Continuous collector current		I_C	8	A
Continuous base current		I_B	0.3	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 1)		P_{tot}	70	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 2)		P_{tot}	2	W
Operating free-air temperature range		T_A	-65 to +150	°C
Operating junction temperature range		T_j	-65 to +150	°C
Storage temperature range		T_{stg}	-65 to +150	°C

NOTES: 1. Derate linearly to 150°C case temperature at the rate of 0.56 W/°C.
2. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = 100 \text{ mA}$	$I_B = 0$	(see Note 3)	BD895 45 BD897 60 BD899 80 BD901 100			V
I_{CEO} Collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$	$I_B = 0$		BD895		0.5	mA
	$V_{CE} = 30 \text{ V}$	$I_B = 0$		BD897		0.5	
	$V_{CE} = 40 \text{ V}$	$I_B = 0$		BD899		0.5	
	$V_{CE} = 50 \text{ V}$	$I_B = 0$		BD901		0.5	
I_{CBO} Collector cut-off current	$V_{CB} = 45 \text{ V}$	$I_E = 0$		BD895		0.2	mA
	$V_{CB} = 60 \text{ V}$	$I_E = 0$		BD897		0.2	
	$V_{CB} = 80 \text{ V}$	$I_E = 0$		BD899		0.2	
	$V_{CB} = 100 \text{ V}$	$I_E = 0$		BD901		0.2	
	$V_{CB} = 45 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	BD895		2	
	$V_{CB} = 60 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	BD897		2	
	$V_{CB} = 80 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	BD899		2	
	$V_{CB} = 100 \text{ V}$	$I_E = 0$	$T_C = 100^\circ\text{C}$	BD901		2	
I_{EBO} Emitter cut-off current	$V_{EB} = 5 \text{ V}$	$I_C = 0$	(see Notes 3 and 4)			2	mA
h_{FE} Forward current transfer ratio	$V_{CE} = 3 \text{ V}$	$I_C = 3 \text{ A}$	(see Notes 3 and 4)	750			
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = 12 \text{ mA}$	$I_C = 3 \text{ A}$	(see Notes 3 and 4)			2.5	V
$V_{BE(on)}$ Base-emitter voltage	$V_{CE} = 3 \text{ V}$	$I_C = 3 \text{ A}$	(see Notes 3 and 4)			2.5	V
V_F Parallel diode forward voltage	$I_F = 8 \text{ A}$					3.5	V

NOTES: 3. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance			1.79	$^\circ\text{C/W}$
$R_{\theta JA}$ Junction to free air thermal resistance			62.5	$^\circ\text{C/W}$

resistive-load-switching characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS [†]			MIN	TYP	MAX	UNIT
t_{on} Turn-on time	$I_C = 3 \text{ A}$	$I_{B(on)} = 12 \text{ mA}$	$I_{B(off)} = -12 \text{ mA}$		1		μs
t_{off} Turn-off time	$V_{BE(off)} = -3.5 \text{ V}$	$R_L = 10 \Omega$	$t_p = 20 \mu\text{s}$, dc $\leq 2\%$		5		μs

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

TYPICAL CHARACTERISTICS

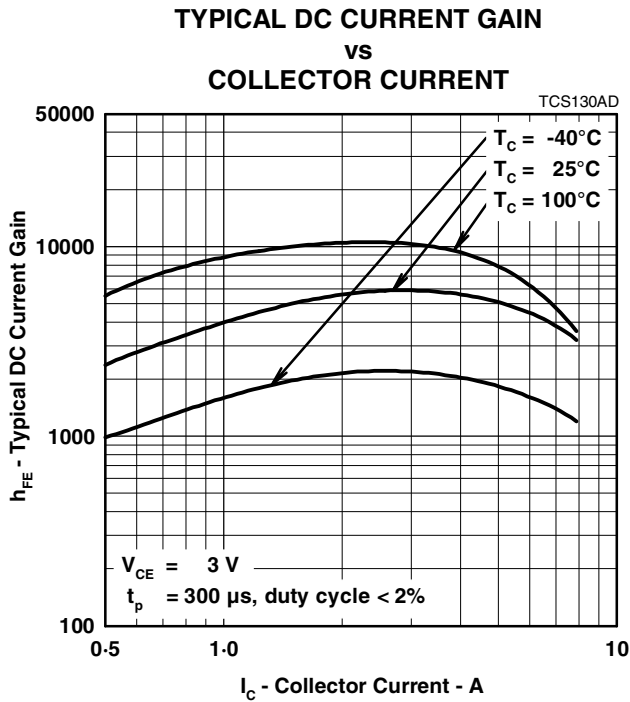


Figure 1.

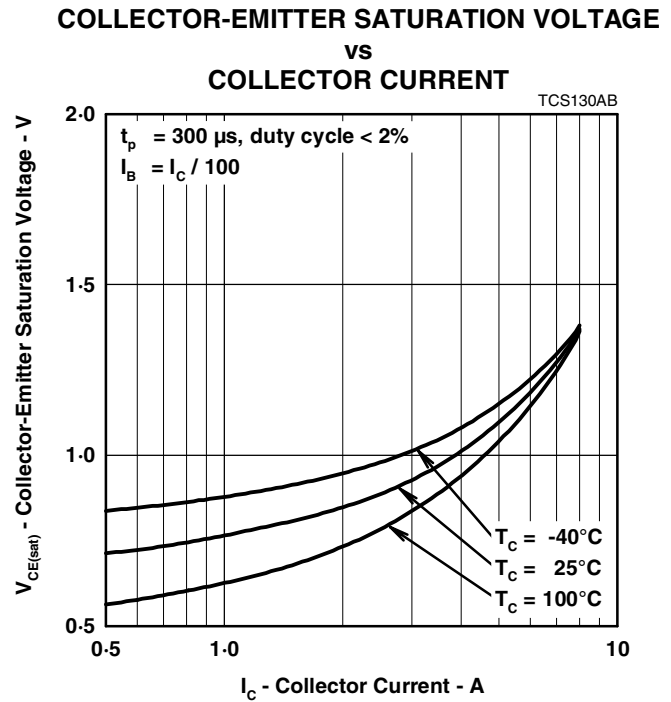


Figure 2.

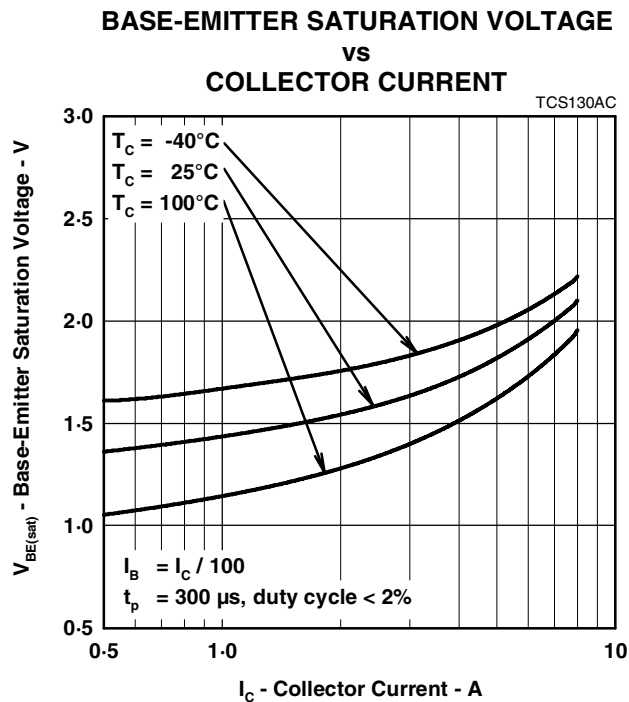


Figure 3.

PRODUCT INFORMATION

MAXIMUM SAFE OPERATING REGIONS

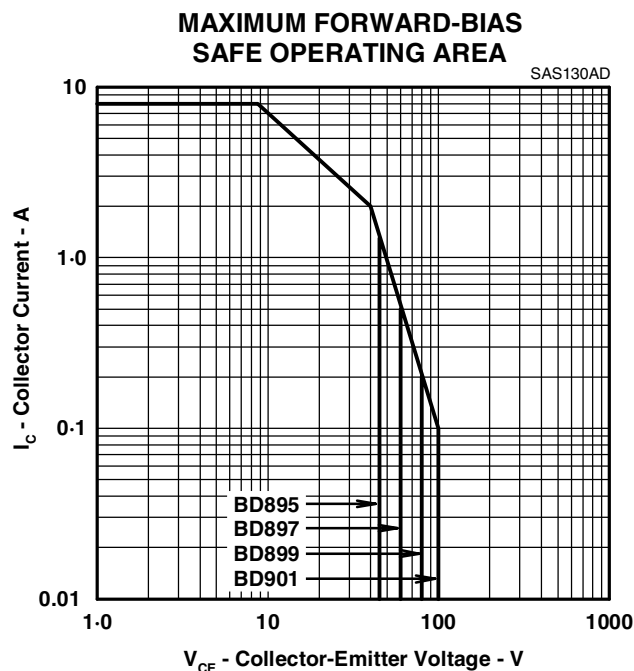


Figure 4.

THERMAL INFORMATION

MAXIMUM POWER DISSIPATION vs CASE TEMPERATURE

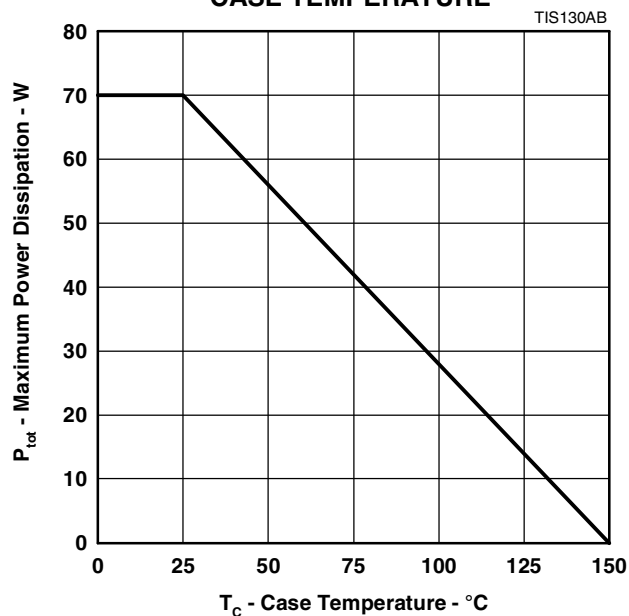


Figure 5.

PRODUCT INFORMATION

AUGUST 1993 - REVISED SEPTEMBER 2002
Specifications are subject to change without notice.